#### Zener Diodes

Panasonic

# **MAZTxxxH** Series

### Silicon planar type

For surge absorption circuit

#### Features

- Two elements anode-common type
- Power dissipation  $P_D$  : 150 mW

#### Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit
Power dissipation *	$P_{D}$	150	mW
Junction temperature	Tj	150	°C
Storage temperature	T <sub>stg</sub>	-55 to +150	°C

Note) \*:  $P_D = 150 \text{ mW}$  achieved with a printed circuit board.

- Package
- Pin Name SSMini3-F2
- Pin Name
- 1: Cathode 1
- 2: Cathode 2
- 3: Anode

#### Marking Symbol

Refer to the list of the electrical characteristics within part numbers

Internal Connection



#### Common Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol		Conditions	Mi	n Typ	Max	Unit
Zener voltage*	VZ	IZ	Specified value				V
Zener rise operating resistance	R <sub>ZK</sub>	IZ	Specified value	Refer to the list of the — —electrical characteristics —			Ω
Zener operating resistance	R <sub>Z</sub>	IZ	Specified value	within pa		Ω	
Reverse current	I <sub>R</sub>	V <sub>R</sub>	Specified value				μΑ

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

2. Electrostatic breakdown voltage:  $\pm 10 \text{ kV}$ 

Test method: IEC1000-4-2 (C = 150 pF, R = 330  $\Omega$ , Contact discharge: 10 times)

3. \*: The temperature must be controlled 25°C for  $V_{\rm Z}$  mesurement.

 $V_Z$  value measured at other temperature must be adjusted to  $V_Z\,(25^\circ C)$ 

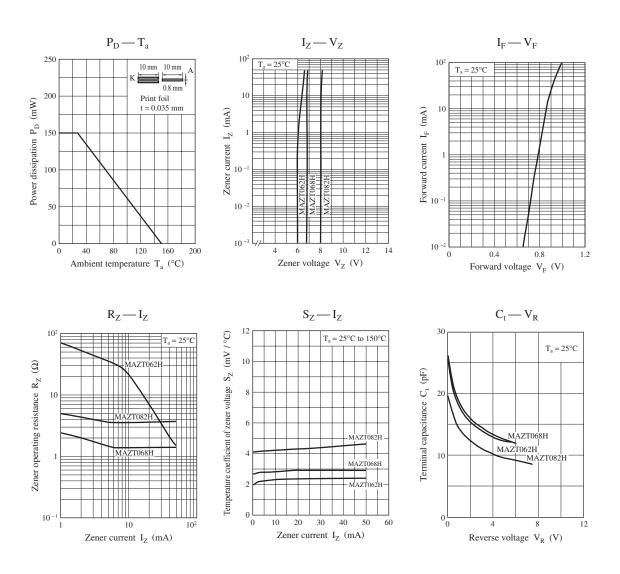
 $V_Z$  guaranted 20 ms after current flow.

### Panasonic

Part number	Zener voltage V <sub>Z</sub> (V)		Reverse current I <sub>B</sub> (mA)		$\begin{array}{c} \text{Zener} \\ \text{operating} \\ \text{resistance} \\ \text{R}_{Z}\left(\Omega\right) \end{array} \begin{array}{c} \text{Zener rise} \\ \text{operating} \\ \text{resistance} \\ \text{R}_{ZK}\left(\Omega\right) \end{array}$		Marking symbol		
		I	1	Ι <sub>Ζ</sub>		V <sub>R</sub>	-	$I_{Z} = 0.5 \text{ mA}$	
	Min	Nom	Max	(mA)	Max	(V)	Max	Max	
MAZT062H	5.8	6.2	6.6	5	0.2	4	50	100	6.2Z
MAZT068H	6.4	6.8	7.2	5	0.1	4	30	60	6.8Z
MAZT082H	7.7	8.2	8.7	5	0.1	5	30	60	8.2Z

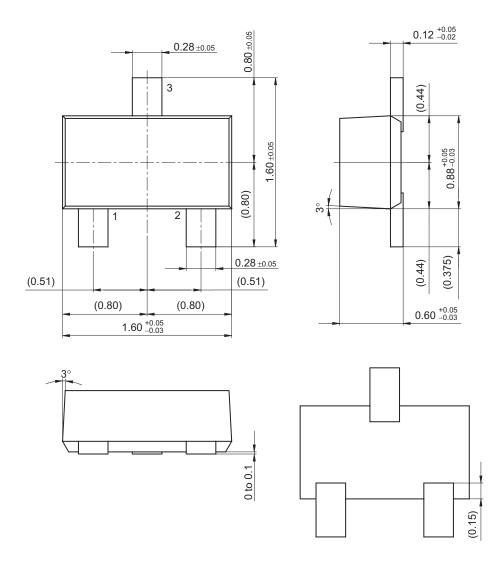
Electrical characteristics w	vithin part numbers	$T_a = 25^{\circ}C \pm 3^{\circ}C$
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Note) \*:  $I_Z = 1.0 \text{ mA}$ 



### SSMini3-F2

Unit: mm



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